

Docket No.: 050432-0657

PATENT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of : Customer Number: 20277
: Confirmation Number: 9931
MARK T. RAMSBEY, et al. :
: Group Art Unit: 2822
Application No.: 10/718,707 :
: Examiner: Duong, Khanh B.
Filed: November 24, 2003 :
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For: METHOD FOR FORMING NITROGEN-RICH REGIONS IN NON-VOLATILE SEMICONDUCTOR MEMORY DEVICES (AS TWICE AMENDED)

AMENDMENT

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

The following Amendment and Remarks are submitted in response to the Office Action dated May 4, 2005. Please amend the above-identified application as follows.